TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (L^2 - π -MOSV)

2SJ402

DC-DC Converter, Relay Drive and Motor Drive Applications

• 4-V gate drive

• Low drain-source ON resistance : $R_{DS(ON)} = 29 \text{ m}\Omega \text{ (typ.)}$

High forward transfer admittance : |Y_{fs}| = 23 S (typ.)

• Low leakage current : I_{DSS} = -100 μA (max) (V_{DS} = -60 V)

• Enhancement mode : $V_{th} = -0.8$ to -2.0 V ($V_{DS} = -10$ V, $I_{D} = -1$ mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	-60	$(\checkmark \lor)$
Drain-gate voltage (R _{GS} = 20 kΩ)		V_{DGR}	-60	V
Gate-source voltage		V _{GSS}	±20	\checkmark
Drain current	DC (Note 1)	I _D	-30	→ A
	Pulse(Note 1)	I _{DP}	-120	Α
Drain power dissipation (Tc = 25°C)		PD	100	W
Single pulse avalanche energy (Note 2)		E _{AS}	936	(mJ
Avalanche current		IAR)) -30	A
Repetitive avalenche energy (Note 3)		EAR	10	mJ
Channel temperature		(T _{ch}))	150	//°c
Storage temperature range		Tstg	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

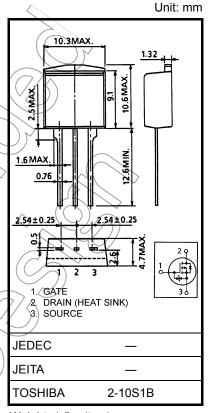
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	1.25	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

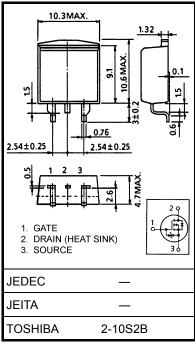
Note 2: V_{DD} = -50 V, T_{ch} = 25°C (initial), L = 747 μ H, R_G = 25 Ω , I_{AR} = -30 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.



Weight: 1.5 g (typ.)



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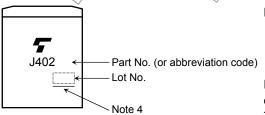
Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	irrent	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	_	_	±10	μΑ
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = -60 V, V _{GS} = 0 V	_	_	-100	μΑ
Drain-source br	eakdown voltage	V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-60	_	_	V
Gate threshold v	oltage	V _{th}	V _{DS} = -10 V, I _D = -1 mA	-0.8	_	-2.0	V
Drain-source O	N registance		V _{GS} = -4 V, I _D = -15 A) 46	60	mΩ
Drain-source ON resistance		R _{DS} (ON)	V _{GS} = -10 V, I _D = -15 A	<u> </u>	29	38	11122
Forward transfer	r admittance	Y _{fs}	V _{DS} = -10 V, I _D = -15 A)14	23		S
Input capacitano	e	C _{iss}		_	3300	_	
Reverse transfe	r capacitance	C _{rss}	V _{DS} = −10 V, V _{GS} = 0 V, f = 1 MHz	_	460	_	pF
Output capacita	nce	Coss		_	1450		
Switching time	Rise time	t _r	V _{GS} OV I ID= 15A V _{OUT}	- (20	∕>	
	Turn-on time	t _{on}	VOUT RL= 2Ω		25) _	ns
	Fall time	t _f	$V_{DD} = -30V$		35	-	115
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\mathbf{W}} = 10 \mu s$) –	130	_	
Total gate char plus gate-drain)	ge (Gate-source	Qg		_	110	_	
Gate-source charge		Q _{gs}	$V_{DD} \approx -48 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -30 \text{ A}$		75	_	nC
Gate-drain ("mil	ler") charge	Qgd		_	35	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

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Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	1 _{DR}		_	_	-30	А
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	-120	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = -30/A, V _{GS} = 0 V	_	_	1.7	V
Reverse recovery time	t _{rr}	I _{DR} = -30 A, V _{GS} = 0 V	1	100	1	ns
Reverse recovery charge	Qrr	dl _{DR} / dt = 50 A / μS		0.16	_	μC



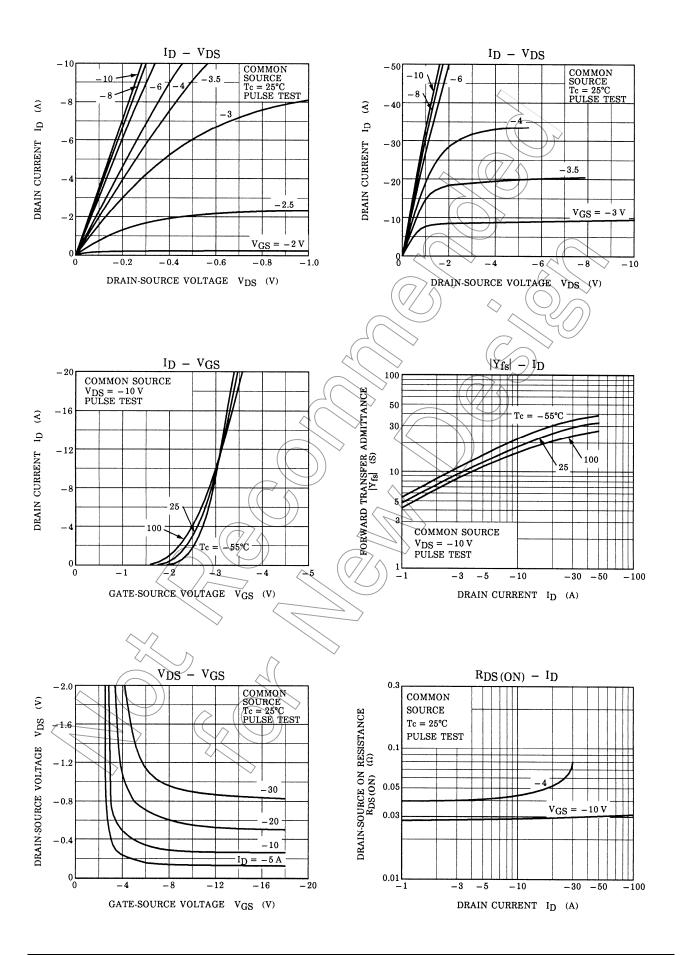


Note 4: A line under a Lot No. identifies the indication of product Labels.

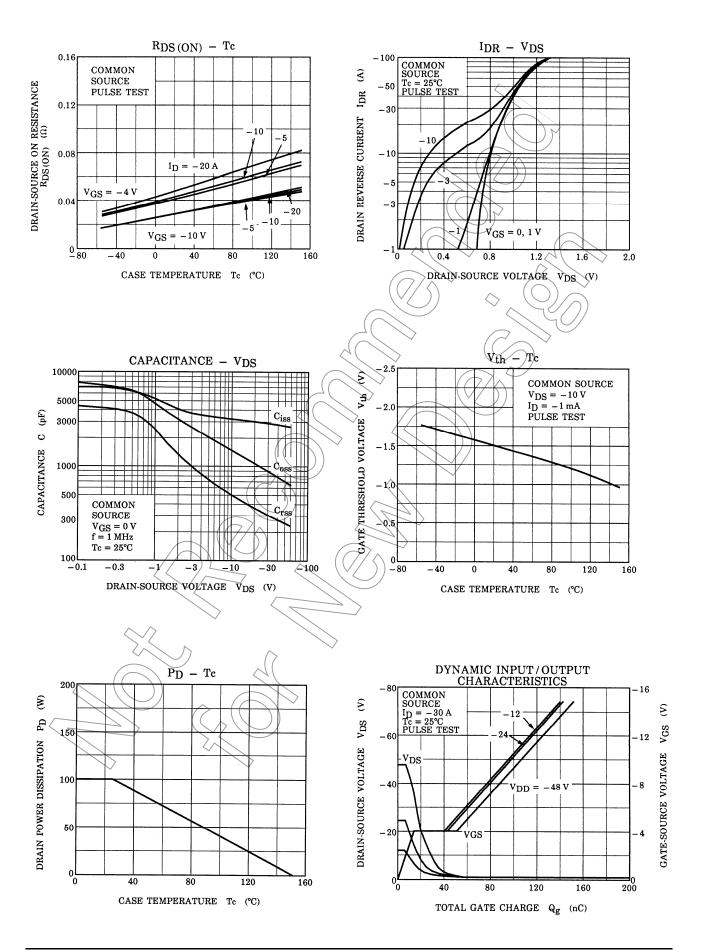
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

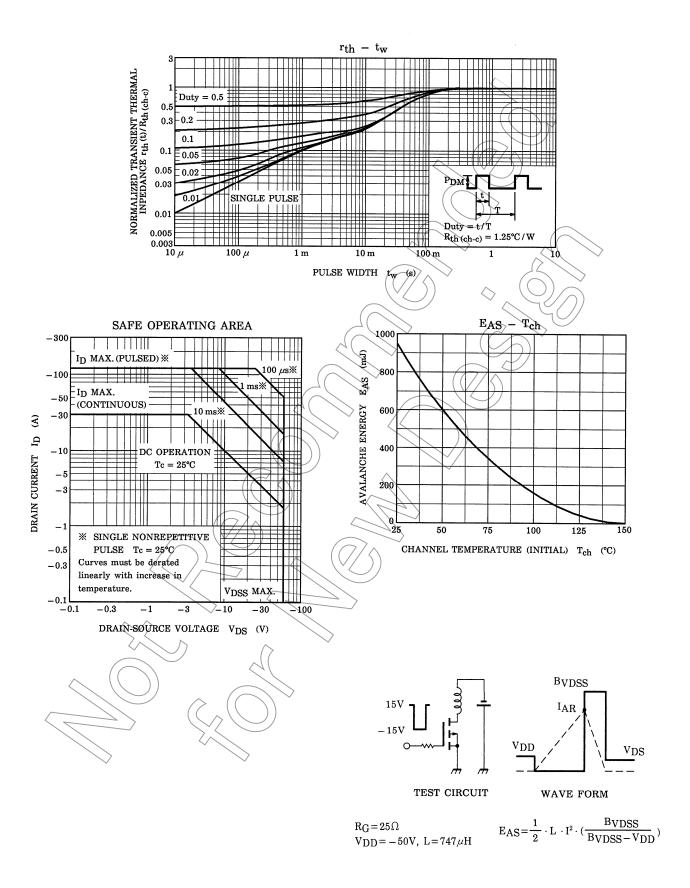
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2 2009-09-29



3 2009-09-29





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6